



BC846BLP4

65V NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

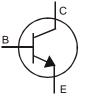
- Low Collector-Emitter Saturation Voltage, VCE(sat) .
- Ultra-Small Leadless Surface Mount Package •
- Totally Lead-Free & Fully RoHS compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

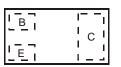
- Case: X2-DFN1006-3 ٠
- Case Material: Molded Plastic, "Green" Molding Compound. • UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.0009 grams (Approximate)

X2-DFN1006-3

Bottom View



Device Symbol



Top View Device Schematic

Ordering Information (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BC846BLP4-7B	3S	7	8	10,000

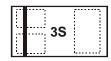
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. 2. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

3S = Product Type Marking Code

3. For packaging details, go to our website at http://www.diodes.com.

Marking Information

Notes:



Top View Bar Denotes Base and Emitter Side

BC846BLP4 Document number: DS35751 Rev. 1 - 2

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Maximum Ratings $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	80	V
Collector-Emitter Voltage	V _{CEO}	65	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Current - Continuous	Ι _C	100	mA
Peak Collector Current	I _{CM}	200	mA
Peak Emitter Current	I _{EM}	200	mA

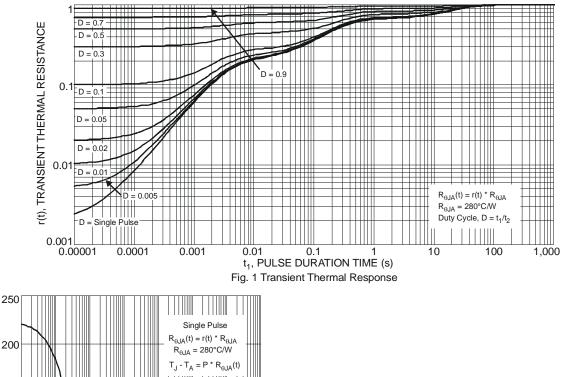
Thermal Characteristics @TA = 25°C unless otherwise specified

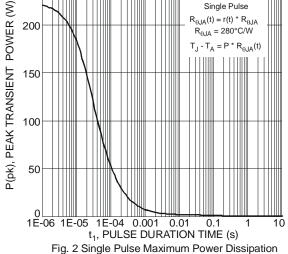
Characteristic	Symbol	Value	Unit		
Power Dissinction	(Note 4)		0.41	w	
Power Dissipation	(Note 5)	P _D	1.05		
Thermal Resistance, Junction to Ambient	(Note 4)	D	302	°C/W	
mermar Resistance, Junction to Ambient	(Note 5)	R _{θJA}	119		
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C	

Notes: 4. Device mounted on FR-4 PCB with minimum recommended pad layout, in still air conditions;

5. Device mounted on 25mm X 25mm FR-4 PCB with high coverage of single sided 2 oz copper, in still air conditions;

Typical Thermal Characteristics



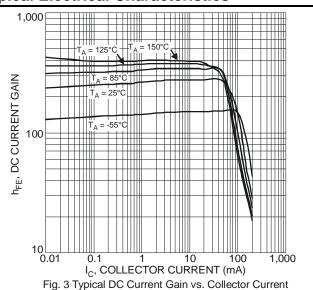


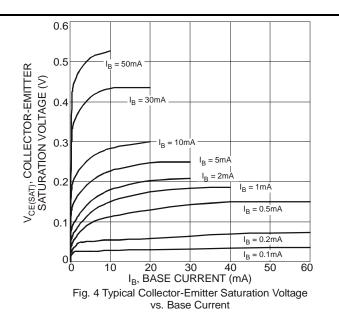


Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition	
OFF CHARACTERISTICS	Cymbol	WIIII	тур	Max	Unit		
Collector-Base Breakdown Voltage	BV _{CBO}	80			V	$I_{\rm C} = 100 \mu A, I_{\rm E} = 0$	
Collector-Emitter Breakdown Voltage (Note 5)	BV _{CEO}	65			V	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0$	
Emitter-Base Breakdown Voltage	BV _{EBO}	6			V	$I_{\rm E} = 100\mu A, I_{\rm C} = 0$	
Collector Cutoff Current	ICES			15	nA	$V_{CE} = 65V$	
Collector Cutoff Current	I _{CBO}	_	_	15 5.0	nA μA	V _{CB} = 40V V _{CB} = 30V, T _A = 150°C	
ON CHARACTERISTICS (Note 5)	•					•	
DC Current Gain	h _{FE}	200	290	450		$V_{CE} = 5V, I_{C} = 2.0mA$	
Collector-Emitter Saturation Voltage	V _{CE(sat)}		90 200	250 600	mV	$I_{C} = 10mA$, $I_{B} = 0.5mA$ $I_{C} = 100mA$, $I_{B} = 5.0mA$	
Base-Emitter Saturation Voltage	V _{BE(sat)}		700 900	900	mV	$I_{C} = 10$ mA, $I_{B} = 0.5$ mA $I_{C} = 100$ mA, $I_{B} = 5.0$ mA	
Base-Emitter Voltage	V _{BE(on)}	580 —	660 —	700 770	mV	$V_{CE} = 5V$, $I_C = 2.0mA$ $V_{CE} = 5V$, $I_C = 10mA$	
SMALL SIGNAL CHARACTERISTICS (Note 5)						· ·	
Input Capacitance	Cibo	_	6.7		pF	V _{CB} = 5V, f = 1.0MHz	
Output Capacitance	Cobo		1.76		pF	V _{CB} = 10V, f = 1.0MHz	
Current Gain-Bandwidth Product	f _T	100	300		MHz	$V_{CE} = 5V, I_{C} = 10mA, f = 100MHz$	
Noise Figure	NF	_	2	10	dB	$V_{CE} = 5V$, $I_C = 200\mu$ A, $R_S = 2.0k\Omega$, f = 1.0kHz, Δf = 200Hz	
Delay time	t _d	-	11.2	-	ns	$V_{CC} = 30V,$ $I_{C} = 150mA,$ $I_{B1} = I_{B2} = 15mA$	
Rise time	tr	-	59.7	-	ns		
Storage time	ts	-	190.8	-	ns		
Fall time	t _f	-	108.6	-	ns		

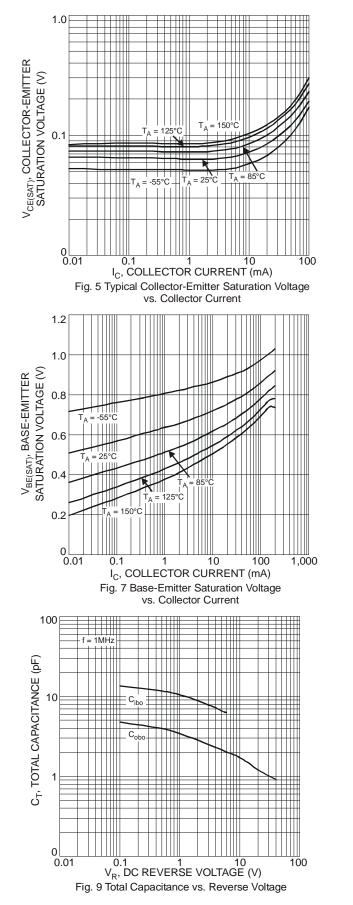
Notes: 5. Measured under pulsed conditions. Pulse width = 300μ s. Duty cycle $\leq 2\%$.

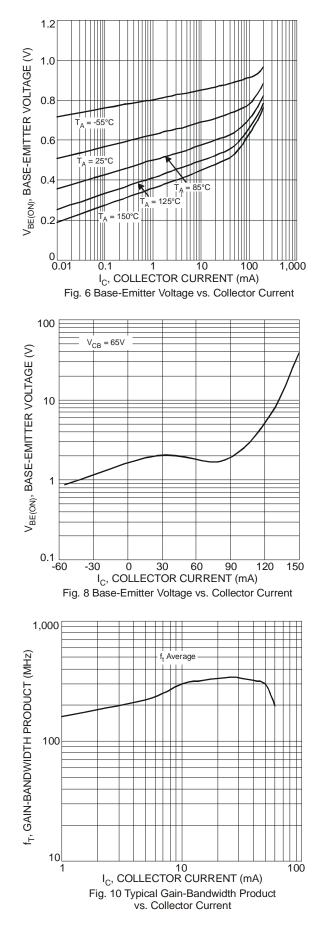




Typical Electrical Characteristics

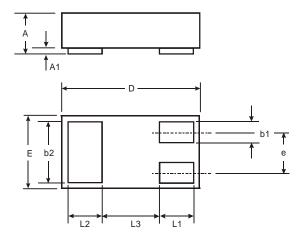






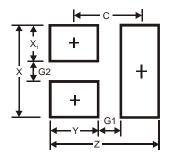


Package Outline Dimensions



X2-DFN1006-3				
Dim	Min	Max	Тур	
Α		0.40		
A1	0	0.05	0.03	
b1	0.10	0.20	0.15	
b2	0.45	0.55	0.50	
D	0.95	1.05	1.00	
Е	0.55	0.65	0.60	
е			0.35	
L1	0.20	0.30	0.25	
L2	0.20	0.30	0.25	
L3			0.40	
All Dimensions in mm				

Suggested Pad Layout



Dimensions	Value (in mm)
Z	1.1
G1	0.3
G2	0.2
Х	0.7
X1	0.25
Ý	0.4
C	0.7



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